NSN 5961-01-009-6325

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-009-6325 **Inclosure Material:** Ceramic and metal **Overall Length:** 1.750 inches **Overall Height:** 1.750 inches **Overall Width:** 1.062 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 1.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 off-state voltage, rms total **Current Rating Per Characteristic:** 110.00 amperes drain current horsepower metric **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector peak **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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